

WHAT THE INVENTION CLAIMED IS

1. A non-volatile memory storage integrated circuit comprising a controller IC, a NAND IC and a memory IC, wherein said controller IC has a USB transmission interface terminal.

5 2. The non-volatile memory storage integrated circuit according to claim 1, wherein said controller IC comprises an I/O controller interface terminal.

3. The non-volatile memory storage integrated circuit according to claim 1, wherein said controller IC comprises a memory card interface terminal.

10 4. The non-volatile memory storage integrated circuit according to claim 2, wherein said controller IC comprises a memory interface terminal and an I/O controller interface terminal.

5. The non-volatile memory storage integrated circuit according to claim 3, wherein said controller IC comprises a USB transmission interface terminal and a memory interface terminal.

15 6. The non-volatile memory storage integrated circuit according to claim 1, wherein said controller IC comprises an I/O controller interface terminal and a memory card interface terminal.

20 7. The non-volatile memory storage integrated circuit according to claim 6, said controller IC comprises a memory card interface terminal, a USB transmission interface terminal and a memory interface terminal.

8. The non-volatile memory storage integrated circuit according to claim 1, wherein said controller IC comprises a built-in ECC and calculation means.

9. The non-volatile memory storage integrated circuit according to claim 1, wherein said memory IC is a NOR IC or a SRAM IC.

10. The non-volatile memory storage integrated circuit according to claim 1, wherein said non-volatile memory storage integrated circuit is packaged into a Chip Size
5 Package (CSP).

11. The non-volatilized memory storage integrated circuit according to claim 1, wherein said non-volatile memory storage integrated circuit is packaged into a Ball Grid
Array (BGA).

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